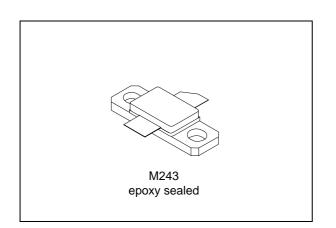
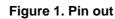


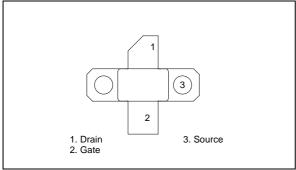
RF power transistor from the LdmoST family of n-channel enhancement-mode lateral MOSFETs

Datasheet - production data



life.augmented





Features

- Excellent thermal stability
- Common source configuration
- P_{OUT} (@28 V) = 45 W with 16 dB gain @ 1600 MHz
- BeO free package
- In compliance with the 2002/95/EC European directive

Description

The LET16045C is a common source N-channel enhancement-mode lateral field-effect RF power transistor designed for broadband commercial and industrial applications at frequencies up to 1.6 GHz. The LET16045C is designed for high gain and broadband performance operating in common source mode at 28 V. It is ideal for INMARSAT satellite communications.

Table 1. Device summary

Order code	Package	Branding
LET16045C	M243	LET16045C

This is information on a product in full production.

Maximum ratings 1

Table 2. Absolute maximum ratings (T _{CASE} = 25 °C)						
Symbol	Parameter	Value	Unit			
V _{(BR)DSS}	Drain-source voltage	80	V			
V _{GS}	Gate-source voltage	-0.5 to +15	V			
۱ _D	Drain current	9	А			
P _{DISS}	Power dissipation (@ T _C = 70 °C)	100	W			
TJ	Max. operating junction temperature	200	°C			
T _{STG}	Storage temperature	-65 to +150	°C			

able 2. Abso	olute maximun	n ratings (1	_{CASE} = 25 °C)
--------------	---------------	--------------	--------------------------

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{th(JC)}	Junction-case thermal resistance	1.3	°C/W



2 Electrical characteristics

T_C = 25 °C

Symbol	Test conditions	Min.	Тур.	Max.	Unit
V _{(BR)DSS}	V_{GS} = 0 V; I _{DS} = 10 mA	80			V
I _{DSS}	V _{GS} = 0 V; V _{DS} = 28 V			1	μA
I _{GSS}	$V_{GS} = 20 \text{ V}; V_{DS} = 0 \text{ V}$			1	μA
V _{GS(Q)}	V _{DS} = 28 V; I _D = 300 mA	2.0		5.0	V
V _{DS(ON)}	V _{GS} = 10 V; I _D = 3 A			1.1	V
G _{FS}	V _{DS} = 10 V; I _D = 3 A	2.5			mho
C _{ISS}	V _{GS} = 0 V; V _{DS} = 28 V; f = 1 MHz		58		pF
C _{OSS}	V_{GS} = 0 V; V_{DS} = 28 V; f = 1 MHz		29		pF
C _{RSS}	$V_{GS} = 0 V; V_{DS} = 28 V; f = 1 MHz$		0.8		pF

Table 4. Static

Table 5. Dynamic

Symbol	Test conditions	Min.	Тур.	Max.	Unit
P _{OUT}	$V_{DD} = 28 \text{ V}; \text{ I}_{DQ} = 400 \text{ mA}; \text{ P}_{IN} = 2 \text{ W}$	45	54		W
G _{PS}	V _{DD} = 28 V; I _{DQ} = 400 mA; P _{OUT} = 45 W	15	16		dB
h _D	V _{DD} = 28 V; I _{DQ} = 400 mA; P _{OUT} = 45 W	50	55	-	%
Load mismatch	V_{DD} = 28 V; I_{DQ} = 400 mA; P_{OUT} = 50 W; f = 1600 MHz All phase angles		20:1		VSWR

Table 6. Impedance data

Frequency (MHz)	Z source (Ω)	Z load (Ω)
1600	1.1 - j1.6	1.1 - j0.6



3 Typical performances

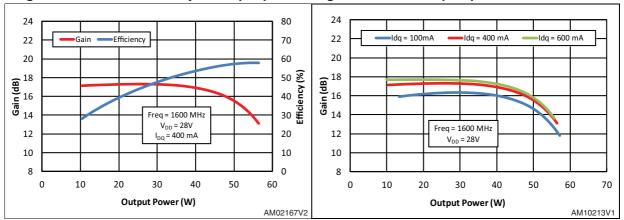
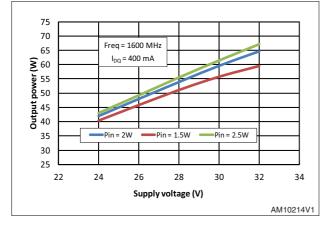


Figure 2. Gain and efficiency vs output power Figure 3. Gain vs ouptut power and bias current

Figure 4. Ouptut power vs drain supply voltage





4 Board layout, schematic and BOM

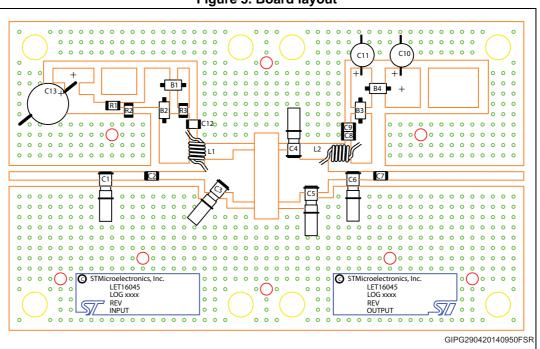
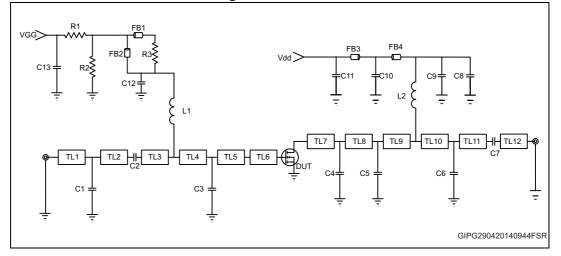


Figure 5. Board layout

Figure 6. Schematic





ltem	Item Qty Part number Vendor Description				
	ς.,			-	
R1	1	CR1206-8W-561JB	VENKEL	560 OHM, 1/8W surface mount chip resistor	
R2	1	CR1206-8W-132JB	VENKEL	1.3K OHM, 1/8W surface mount chip resistor	
R3	1	CR1206-8W-100JB	VENKEL	10 OHM, 1/8W surface mount chip resistor	
FB1,2,3,4,	4	2743021447	FAIR-RITE CORP	Surface Mount EMI sheild bead	
C1,C4,C5,C6	4		JOHANSON	0.6-4.5pF giga trim variable capacitor	
C2,C7,C9,C12	4	ATC100B470XXXX	ATC	47 pF chip capacitor	
C3	1	27291PC	JOHANSON	0.8-8pF giga trim variable capacitor	
C8	1	ATC100B330XXXX	ATC	33pF chip capacitor	
C10	1			330uF, 50V electrolytic capacitor	
C11	1			10uF, 63V electrolytic capacitor	
C13	1			100uF, 63V electrolytic capacitor	
L1, L2	2	1812SMS-33NJ	Coilcraft	33 nH coil	
TL1, TL2	2			L= 1.350in [34.29mm] W=0.082in [2.080mm]	
TL3	1			L= 0.469in [11.91mm] W=0.080in [2.020mm]	
TL4, TL5	2			L= 0.277in [7.03mm] W=0.323in [8.210mm]	
TL6	1			L= 0.207in [5.26mm] W=0.506in [12.85mm]	
TL7	1			L= 0.208in [5.28mm] W=0.506in [12.85mm]	
TL8,TL9	2			L= 0.275in [6.98mm] W=0.324in [8.230mm]	
TL10,TL11	2			L= 0.470in [11.93mm] W=0.080in [2.020mm]	
TL12	1			L= 1.351in [34.33mm] W=0.082in [2.080mm]	
Board 3X5	1		Rogers Corp	Er=2.55 t=0.0026in h=0.030in	

Table 7. Component list



5 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

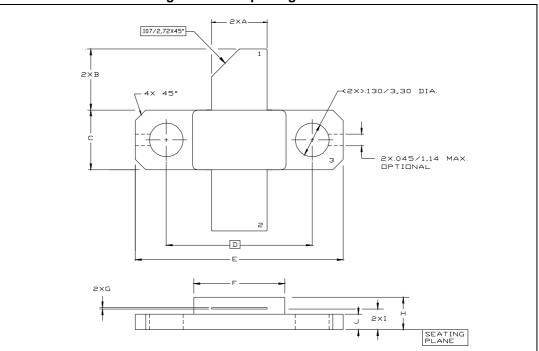


Figure 7. M243 package dimensions

Dim	Dim.			inch		
Dim.	Min.	Тур	Max.	Min.	Тур	Max.
А	5.21		5.72	0.205		0.225
В	5.46		6.48	0.215		0.255
С	5.59		6.1	0.22		0.24
D		14.27			0.562	
E	20.07		20.57	0.79		0.81
F	8.89		9.4	0.35		0.37
G	0.1		0.15	0.004		0.006
Н	3.18		4.45	0.125		0.175
I	1.83		2.24	0.072		0.088
J	1.27		1.78	0.05		0.07



6 Revision history

Date	Revision Changes	
14-Sep-2011	1	Initial release.
04-Nov-2011	2	Updated Table 3: Thermal data, Table 4: Static, Table 5: Dynamic and Figure 3: Gain vs ouptut power and bias current. Inserted Table 6: Impedance data and Figure 2: Gain and efficiency vs output power and Figure 4: Ouptut power vs drain supply voltage.
29-Apr-2014	3	Added Section 4: Board layout, schematic and BOM.

Table 9. Document revision history



Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

ST PRODUCTS ARE NOT DESIGNED OR AUTHORIZED FOR USE IN: (A) SAFETY CRITICAL APPLICATIONS SUCH AS LIFE SUPPORTING, ACTIVE IMPLANTED DEVICES OR SYSTEMS WITH PRODUCT FUNCTIONAL SAFETY REQUIREMENTS; (B) AERONAUTIC APPLICATIONS; (C) AUTOMOTIVE APPLICATIONS OR ENVIRONMENTS, AND/OR (D) AEROSPACE APPLICATIONS OR ENVIRONMENTS. WHERE ST PRODUCTS ARE NOT DESIGNED FOR SUCH USE, THE PURCHASER SHALL USE PRODUCTS AT PURCHASER'S SOLE RISK, EVEN IF ST HAS BEEN INFORMED IN WRITING OF SUCH USAGE, UNLESS A PRODUCT IS EXPRESSLY DESIGNATED BY ST AS BEING INTENDED FOR "AUTOMOTIVE, AUTOMOTIVE SAFETY OR MEDICAL" INDUSTRY DOMAINS ACCORDING TO ST PRODUCT DESIGN SPECIFICATIONS. PRODUCTS FORMALLY ESCC, QML OR JAN QUALIFIED ARE DEEMED SUITABLE FOR USE IN AEROSPACE BY THE CORRESPONDING GOVERNMENTAL AGENCY.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

> ST and the ST logo are trademarks or registered trademarks of ST in various countries. Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2014 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com



DocID022224 Rev 3